

TOSHIBA PHOTOCOUPLER PHOTO RELAY

T L P 3 1 1 3

MEASUREMENT INSTRUMENTS LOGIC IC TESTERS / MEMORY TESTERS BOARD TESTERS / SCANNERS

The TOSHIBA TLP3113 Mini-flat photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP3113 consists of a GaAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package.

Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency mearsuring instruments.

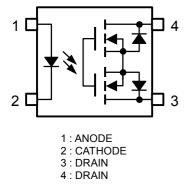
FEATURES

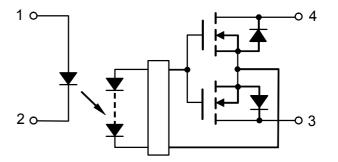
- 4 pin SOP (2.54SOP4)
- : 2.1 mm high, 2.54 mm pitch
- 1-Form-A
- Peak Off-State Voltage : 40 V (MIN.)
- Trigger LED Current : 4 mA (MAX.)
- On-State Current : 80 mA (MAX.)
- On-State Resistance
- Output Capacitance : 1.4 j

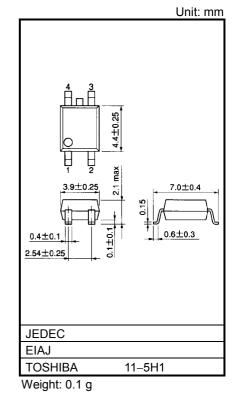
PIN CONFIGURATION (TOP VIEW)

- Isolation Voltage
- : 35 Ω (MAX.), 25 Ω (TYP.)
- : 1.4 pF (MAX.), 0.6 pF (TYP.)
- : 1500 Vrms (MIN.)

SCHEMATIC







MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
D	Forward Current	١ _F	50	mA
	Forward Current Derating (Ta \ge 25°C)	∆I _F /°C	-0.5	mA/°C
Ц	Reverse Voltage	V _R	5	V
	Junction Temperature	Tj	125	°C
DETECTOR	Off-State Output Terminal Voltage	V _{OFF}	40	V
	On-State Current	I _{ON}	80	mA
	On-State Current Derating (Ta \ge 25°C)	∆l _{ON} /°C	-0.8	mA/°C
	Junction Temperature	Tj	125	°C
Stora	ge Temperature Range	T _{stg}	-40~125	°C
Opera	ating Temperature Range	T _{opr}	-20~85	°C
Lead	Soldering Temperature (10 s)	T _{sol}	260	°C
Isolat	ion Voltage (AC, 1 minute, R.H. \leq 60%) (NOTE1)	BVS	1500	Vrms

(NOTE1) : Device considered a two-terminal device : Pins 1 and, 2 shorted together, and pins 3 and 4 shorted together.

CAUTION

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}	_	_	32	V
Forward Current	١ _F	10	_	30	mA
On-State Current	I _{ON}	_	_	80	mA
Operating Temperature	T _{opr}	25		60	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25° C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	$V_R = 5 V$			10	μA
	Capacitance	CT	V = 0, f = 1 MHz		15		pF
DETECTOR	Off-State Current	IOFF	V _{OFF} = 30 V, Ta = 50°C	_	_	1000	pА
DETE	Capacitance	C _{OFF}	V = 0, f = 100 MHz, t < 1 s		0.6	1.4	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I _{FT}	I _{ON} = 80 mA	_	_	4	mA
Return LED Current	I _{FC}	I _{OFF} = 10 μA	0.2	0.75	_	mA
On-State Resistance	R _{ON}	I _{ON} = 80 mA, I _F = 5 mA, t < 1 s		25	35	Ω

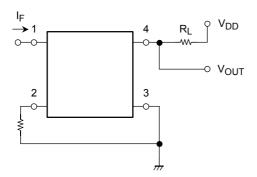
ISOLATION CHARACTERISTICS (Ta = 25°C)

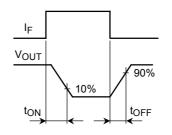
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	CS	$V_{S} = 0 V$, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	5×10^{10}	10 ¹⁴	_	Ω
		AC, 1 minute	1500		_	Vrms
Isolation Voltage	BVS	AC, 1 second (in oil)	_	3000	_	
		DC, 1 minute (in oil)		3000	_	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

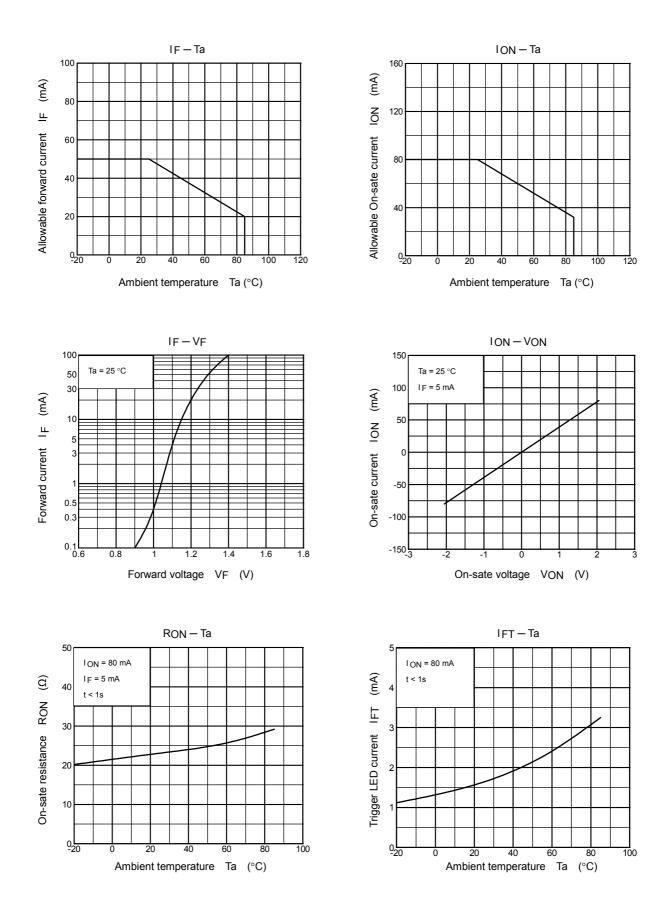
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t _{ON}	R _L = 200 Ω (NOTE 2)	_	_	500	
Turn-off Time	tOFF	V _{DD} = 10 V, I _F = 10 mA		—	500	μS

(NOTE 2) : SWITCHING TIME TEST CIRCUIT

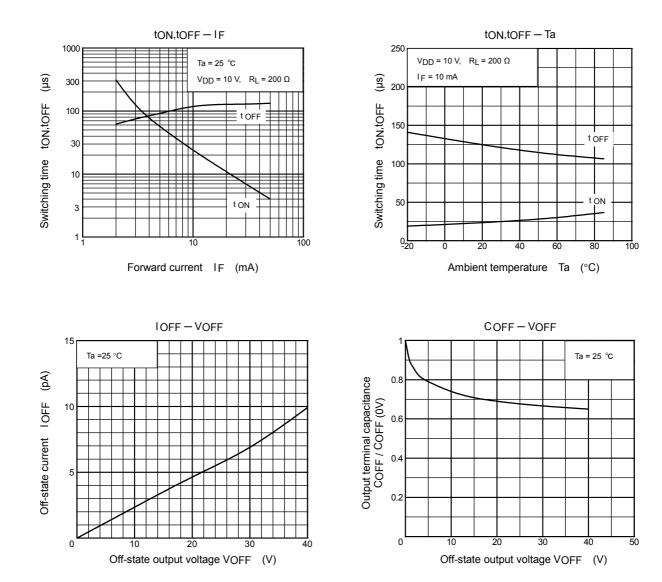




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